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NEAR-FIELD POWER DENSITY EVALUATION REPORT

Applicant Name

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do, 16677, Korea Date of Testing 10/07/2021 - 11/15/2021 Test Site/Location PCTEST, Columbia, MD, USA Document Serial No: 1M2109090103-24.A3L (Rev 1)

FCC ID: A3LSMS906U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

DUT Type: Portable Handset

Application Type: Certification
FCC Rule Part(s): CFR §2.1093
Model: SM-S906U
Additional Model (s): SM-S906U1

Band & Mode	Tx Frequency	Measured psPD	Reported psPD
Band & Mode	MHz	mW/cm²	mW/cm²
n258 24250 - 24450; 24750 - 25250		0.412	0.891
n261	27500 - 28350	0.391	0.891
n260 37000 - 40000		0.458	0.891
Total Exp	osure Ratio	0.	970
Verdict		P/	ASS

Note: This revised Test Report supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them. Test results reported herein relate only to the item(s) tested.

-J Randy Ortanez President

lac-MRA	ACCREDITED CERT #2041.01

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APPENDIX A: POWER DENSITY TEST PLOTS APPENDIX B: SYSTEM VERIFICATION PLOTS APPENDIX C: TOTAL EXPOSURE RATIO

APPENDIX D: DUT ANTENNA DIAGRAM AND TEST SETUP PHOTOGRAPHS

APPENDIX E: PROBE AND VERIFICATION SOURCE CALIBRATION CERTIFICATES

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DEVICE UNDER TEST

1.1 NR FR2 Checklist

NR FR2 Operations Information				
Form Factor Portable Handset				
Subcarrier Spacing (kHz)	120			
Total Number of Supported Uplink CCs (SISO)	2			
Total Number of Supported Uplink CCs (MIMO)	2			
Total Number of Supported DL CCs	8			
CP-OFDM Modulations Supported in UL	QPSK, 16QAM, 64QAM, 256QAM			
DFT-s-OFDM Modulations Supported in UL	PV2 BPSK, QPSK, 16QAM, 64QAM, 256QAM			
LTE Anchor Bands	n258: 2/5/12/14/30/66, n261: 2/5/12/13/48/66, n260: 2/5/12/13/14/30/48/66			
NR FR1 Anchor Bands	n258: 2/5/12/30/66, n261: 2/5/66/77, n260: 2/5/12/30/66/77			
Duplex Type (mmWave)	TDD			

	NR FR2 Channels & Frequencies						
NR Band	Bandwidth Low		M	Mid		High	
INK Dallu	(MHz)	Channel	Frequency (MHz)	Channel	Frequency (MHz)	Channel	Frequency (MHz)
n258	100	2018333	24350.04	2025833	24800.04	2032499	25200.00
n258	50	2018333	24350.04	2025833	24800.04	2032915	25224.96
n261	100	2071667	27550.08	2077915	27924.96	2084165	28299.96
n261	50	2071249	27525.00	2077915	27924.96	2084581	28324.92
n260	100	2229999	37050.00	2254165	38499.96	2278331	39949.92
n260	50	2229599	37026.00	2254165	38499.96	2278749	39975.00

1.2 Time-Averaging Algorithm for RF Exposure Compliance

The device is enabled with Qualcomm® Smart Transmit (GEN2) feature. This feature performs time averaging algorithm in real time to control and manage transmitting power and ensure the time-averaged RF exposure is in compliance with FCC requirements all the time. Refer to Compliance Summary document for detailed description of Qualcomme Smart Transmit. Note that WLAN operations are not enabled with Smart Transmit.

The Smart Transmit algorithm maintains the time-averaged transmit power, in turn, time-averaged RF exposure of SAR_design_target or PD_design_target, below the predefined time-averaged power limit (i.e., Plimit for sub-6 radio, and input.power.limit for 5G mmW NR), for each characterized technology and band (see RF Exposure Part 0 Test Report).

Smart Transmit allows the device to transmit at higher power instantaneously when needed, but manages power limiting to maintain time-averaged transmit power to input.power.limit.

The purpose of this report (Part 1 test) is to demonstrate that the EUT meets FCC PD limits when transmitting in static transmission scenario at maximum allowable time-averaged power level given by input.power.limit.

1.3 **Power Density Design Target and Uncertainty**

Power Density Design Specifications			
PD_design_target (mW/cm²)	0.631		
Design Related Total Uncertainty (dB)	2.0		

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RFV 1 0

1.4 Input Power Specifications

All power density measurements for this device were performed at the *input.power.limit* given in below tables. Input power is per antenna element and polarization for each antenna module. When input.power.limit is calculated to be above the maximum input power, the device is limited to the maximum input power.

Table 1-1
5G mmWave NR n258 M Patch input.power.limit

IVVav	J 1411 112		iten input.pow
Band		Beam ID 2	input.power.limit
n258	0	-	10.3
n258	2	-	9.2
n258	4	-	9.7
n258	6	-	10.0
n258	8	-	9.4
n258	10	-	7.0
n258	11	-	5.5
n258	12	-	7.0
n258	13	-	7.0
n258	18	-	6.6
n258	19	-	6.6
n258	20	-	8.0
n258	24	-	2.2
n258	25	-	2.7
n258	26	_	2.4
n258	27	-	2.9
		-	
n258	28	-	2.7
n258	34	-	2.1
n258	35	-	2.4
n258	36	-	2.7
n258	37	-	3.0
n258	-	128	8.7
n258	-	130	9.3
n258	_	132	9.0
			9.4
n258	-	134	
n258	-	136	9.5
n258	-	138	7.0
n258	-	139	6.1
n258	-	140	5.6
n258	-	141	5.9
n258	-	146	6.2
n258	_	147	6.2
		148	
n258	-		5.2
n258	-	152	2.6
n258	-	153	3.0
n258	-	154	2.6
n258	-	155	1.9
n258	-	156	1.0
n258	-	162	2.9
n258	-	163	2.9
n258	_	164	2.6
n258	-	165	1.4
n258	0	128	5.7
n258	2	130	6.1
n258	4	132	6.2
n258	6	134	6.3
n258	8	136	6.1
n258	10	138	3.6
n258	11	139	2.8
n258	12	140	3.3
n258	13	141	3.0
n258	18	146	3.3
n258	19	147	3.0
n258	20	148	4.0
n258	24	152	-1.1
n258	25	153	-0.6
n258	26	154	-0.7
n258	27	155	-1.0
n258			
	28 34	156	-1.9
		162	-1.0
n258			
n258 n258	35	163	-0.8
n258			-0.8 -0.7

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Table 1-2
5G mmWave NR n258 N Patch input.power.limit

			ten input.power.i
Band	Beam ID 1	Beam ID 2	input.power.limit
n258	1	-	10.0
n258	3	-	11.9
n258	5	-	11.9
n258	7	-	11.6
n258	9	-	11.4
n258	14	-	7.6
n258	15	-	7.1
n258	16	-	7.5
n258	17	1	8.0
n258	21	-	7.8
n258	22	-	7.5
n258	23	-	7.5
n258	29	-	4.3
n258	30	-	4.2
n258	31	-	4.3
n258	32	-	3.0
n258	33	-	3.6
n258	38	-	4.0
n258	39	-	3.8
n258	40	-	3.4
n258	41	-	3.6
	41		10.0
n258 n258	-	129 131	
-	-		10.4
n258	-	133	10.5
n258	-	135	10.3
n258	-	137	11.8
n258	-	142	7.8
n258	-	143	6.6
n258	-	144	7.1
n258	-	145	9.1
n258	-	149	7.3
n258	-	150	6.4
n258	-	151	8.6
n258	-	157	3.6
n258	-	158	2.8
n258	-	159	2.5
n258	-	160	3.1
n258	-	161	3.3
n258	-	166	2.8
n258	-	167	2.6
n258	_	168	2.9
n258	-	169	2.9
n258	1	129	6.5
n258	3	131	7.5
n258	5	133	7.2
	7		7.3
n258	9	135	
n258		137	7.9
n258	14	142	4.1
n258	15	143	4.0
n258	16	144	4.2
n258	17	145	6.0
n258	21	149	4.0
n258	22	150	3.4
n258	23	151	4.4
n258	29	157	-0.3
n258	30	158	-0.8
n258	31	159	-0.3
n258	32	160	-0.4
n258	33	161	-0.2
n258	38	166	-0.5
n258	39	167	-0.7
n258	40	168	-0.3
n258	41	169	-0.4
	_ =		

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Table 1-3
5G mmWave NR n261 M Patch input.power.limit

			ten input.power.i
Band	Beam ID 1	Beam ID 2	input.power.limit
n261	0	-	10.3
n261	2	-	10.9
n261	4	-	10.0
n261	6	-	9.9
n261	8	-	10.1
n261	10	_	8.8
n261	11	_	7.5
		_	
n261	12		7.2
n261	13	-	8.0
n261	18	-	7.6
n261	19	-	7.3
n261	20	-	7.3
n261	24	-	4.6
n261	25	-	3.1
n261	26	-	3.0
n261	27	-	2.4
n261	28	-	4.0
n261	34	-	3.7
n261	35	-	2.7
_		-	
n261	36		2.7
n261	37	- 120	2.9
n261	-	128	8.6
n261	-	130	8.5
n261	-	132	8.5
n261	-	134	8.6
n261	-	136	8.9
n261	-	138	6.4
n261	-	139	5.5
n261	-	140	5.0
n261	_	141	5.3
	_	146	
n261	-		5.6
n261	-	147	5.1
n261	-	148	5.0
n261	-	152	1.7
n261	-	153	1.5
n261	-	154	1.8
n261	-	155	1.5
n261	-	156	1.0
n261	-	162	1.2
n261	-	163	1.8
n261	-	164	1.9
	-		1.4
n261		165	
n261	0	128	5.8
n261	2	130	6.2
n261	4	132	6.1
n261	6	134	5.8
n261	8	136	6.0
n261	10	138	3.9
n261	11	139	3.2
n261	12	140	2.4
n261	13	141	2.7
n261	18	146	3.2
n261			
	19	147	2.9
n261	20	148	2.3
n261	24	152	-1.0
n261	25	153	-1.0
n261	26	154	-0.8
n261	27	155	-1.2
n261	28	156	-1.4
n261	34	162	-1.1
n261	35	163	-1.0
n261	36	164	-0.8
n261	37	165	-1.3
11201	31	103	1.3

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Table 1-4
5G mmWave NR n261 N Patch input.power.limit

IIIIIIV			ten input.power.
Band	Beam ID 1	Beam ID 2	input.power.limit
n261	1	-	9.1
n261	3	-	8.9
n261	5	-	9.0
n261	7	-	8.9
n261	9	-	9.7
n261	14	_	7.8
n261	15	_	5.9
		-	
n261	16	-	5.7
n261	17	-	6.5
n261	21	-	7.0
n261	22	-	5.2
n261	23	-	5.7
n261	29	-	2.7
n261	30	-	2.0
n261	31	-	1.4
n261	32	-	1.7
n261	33	-	2.9
n261	38	-	2.5
n261	39	-	1.7
n261	40	-	1.6
n261	41	-	2.0
n261	-	129	9.2
n261	-	131	9.2
n261	_	133	9.8
n261	-	135	9.2
n261	-	137	8.8
n261	-	142	6.6
n261	-	143	6.6
n261	-	144	5.7
n261	-	145	6.0
n261	-	149	7.0
n261	-	150	6.0
n261	-	151	5.7
	-		
n261	-	157	4.3
n261	-	158	2.1
n261	-	159	2.2
n261	-	160	2.0
n261	-	161	2.9
n261	-	166	3.3
n261	-	167	2.0
n261	_	168	2.1
		169	
n261	- 1		2.3
n261	1	129	5.7
n261	3	131	5.5
n261	5	133	5.9
n261	7	135	5.8
n261	9	137	5.8
n261	14	142	3.7
n261	15	143	2.4
n261	16	144	2.2
		145	
n261	17		2.9
n261	21	149	4.2
n261	22	150	2.5
n261	23	151	2.4
n261	29	157	-0.7
n261	30	158	-1.3
n261	31	159	-1.7
n261	32	160	-1.7
	33	161	-0.7
n261	20	166	
n261	38	166	-0.7
n261 n261	39	167	-1.8
n261			

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Table 1-5
5G mmWave NR n260 M Patch input.power.limit

			teri iriput.power.i
Band	Beam ID 1	Beam ID 2	input.power.limit
n260	0	-	10.5
n260	2	-	11.9
n260	4	-	11.5
n260	6	-	11.7
n260	8	-	11.1
n260	10	_	8.1
n260	11	_	9.1
		_	
n260	12		8.9
n260	13	-	8.1
n260	18	-	8.1
n260	19	-	8.3
n260	20	-	8.9
n260	24	-	5.3
n260	25	-	4.8
n260	26	-	5.8
n260	27	-	5.6
n260	28	-	5.1
n260	34	_	5.6
	35	-	5.3
n260			
n260	36	-	5.7
n260	37	-	5.0
n260	-	128	10.9
n260	-	130	11.0
n260	-	132	10.3
n260	-	134	10.6
n260	-	136	10.6
n260	-	138	7.2
n260	_	139	8.1
n260	_	140	7.7
n260	-	141	8.2
n260	-	146	7.5
n260	-	147	8.0
n260	-	148	8.2
n260	-	152	4.1
n260	-	153	4.6
n260	-	154	3.8
n260	-	155	4.5
n260	_	156	4.0
n260	_	162	4.1
n260	_	163	4.2
	-		
n260		164	4.6
n260	-	165	4.0
n260	0	128	6.8
n260	2	130	7.6
n260	4	132	7.4
n260	6	134	7.3
n260	8	136	6.8
n260	10	138	5.8
n260	11	139	5.4
n260	12	140	3.9
n260	13	141	4.2
n260	18	146	4.2
n260	19	147	4.4
n260	20	148	5.9
n260	24	152	0.8
n260	25	153	1.1
n260	26	154	0.1
n260	27	155	0.6
n260	28	156	0.4
n260	34	162	0.9
n260	35	163	0.9
n260	36	164	0.8
n260	37	165	0.3

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Table 1-6 5G mmWave NR n260 N Patch input.power.limit

Band	Boam ID 1	Beam ID 2	innut nower limit
		Dealli ID Z	input.power.limit
n260	1	-	9.2
n260	3	-	8.3
n260	5	-	8.6
n260	7	-	8.2
n260	9	-	8.5
n260	14	-	5.5
n260	15	-	6.1
n260	16	-	4.9
n260	17	-	5.8
n260	21	-	5.8
n260	22	-	5.8
n260	23	-	5.1
n260	29	_	1.6
n260	30		2.5
		_	
n260	31	-	2.4
n260	32	-	1.0
n260	33	-	2.4
n260	38	-	2.5
n260	39	-	2.2
n260	40	-	1.6
		-	
n260	41		2.0
n260	-	129	6.9
n260	-	131	8.2
n260	-	133	7.9
n260	-	135	7.6
n260	-	137	7.9
n260	_	142	4.8
n260	_	143	5.2
n260	-	144	4.9
n260	-	145	4.7
n260	-	149	4.3
n260	-	150	5.1
n260	-	151	4.8
n260	-	157	1.3
n260	_	158	1.2
	_		
n260	-	159	1.1
n260	-	160	1.4
n260	-	161	1.5
n260	-	166	1.2
n260	-	167	1.0
n260	-	168	2.0
n260	_	169	1.4
	1	129	4.2
n260			
n260	3	131	4.8
n260	5	133	5.0
n260	7	135	4.7
n260	9	137	4.6
n260	14	142	1.8
n260	15	143	1.9
n260	16	144	2.4
	17		
n260		145	2.0
n260	21	149	2.4
n260	22	150	1.7
n260	23	151	2.1
n260	29	157	-2.8
n260	30	158	-1.9
n260	31	159	-2.3
n260	32	160	-2.6
n260	33	161	-2.7
n260	38	166	-2.4
n260	39	167	-2.1
n260	40	168	-2.4
n260	41	169	-2.4
			•

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1.5 DUT Antenna Locations

The table below indicates the surfaces evaluated for near field power density (part 1) evaluation. Refer to RF Exposure Part 0 Test Report for justification of these worst-surfaces

Table 1-7
Device Surfaces

Band	Antenna	Antenna Type	Back	Front	Тор	Bottom	Right	Left
n258	М	Patch	Yes	No	No	No	No	No
n258	N	Patch	Yes	No	No	No	Yes	No
n261	М	Patch	Yes	No	No	No	No	No
n261	N	Patch	Yes	No	No	No	Yes	No
n260	М	Patch	Yes	No	No	No	No	Yes
n260	N	Patch	Yes	No	No	No	Yes	No

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1.6 Simultaneous Transmission Capabilities

According to FCC KDB Publication 447498 D01v06, transmitters are considered to be operating simultaneously when there is overlapping transmission, with the exception of transmissions during network hand-offs with maximum hand-off duration less than 30 seconds.

This device contains multiple transmitters that may operate simultaneously, and therefore requires a simultaneous transmission analysis according to FCC KDB Publication 447498 D01v06 4.3.2 procedures.

Table 1-8 Simultaneous Tx

		muntane				
No.	Capable Transmit Configuration	Head	Body-worn	Wireless Router	Phablet	Notes
1	LTE + 5G NR FR2	Yes	Yes	N/A	Yes	
2	LTE + 2.4 GHz WLAN Ant 1 + 5G NR FR2	Yes	Yes	Yes	Yes	
3	LTE + 2.4 GHz WLAN Ant 2 + 5G NR FR2	Yes	Yes	Yes	Yes	
4	LTE + 2.4 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
5	LTE + 2.4 GHz Bluetooth Ant 1 + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
6	LTE + 2.4 GHz Bluetooth Ant 2 + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
7	LTE + 2.4 GHz Bluetooth MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
8	LTE + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
9	LTE + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
10	LTE + 2.4 GHz WLAN Ant 1 + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
11	LTE + 2.4 GHz WLAN Ant 2 + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
12	LTE + 2.4 GHz WLAN MIMO + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
13	LTE + 2.4 GHz Bluetooth Ant 1 + 5 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
14	LTE + 2.4 GHz Bluetooth Ant 2 + 5 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
15	LTE + 2.4 GHz Bluetooth MIMO + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
16	LTE + 2.4 GHz WLAN Ant 1 + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
17	LTE + 2.4 GHz WLAN Ant 2 + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
18	LTE + 2.4 GHz WLAN MIMO + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
19	LTE + 2.4 GHz Bluetooth Ant 1 + 6 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	N/A	Yes	^Bluetooth Tethering is considered
20	LTE + 2.4 GHz Bluetooth Ant 2 + 6 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	N/A	Yes	^Bluetooth Tethering is considered
21	LTE + 2.4 GHz Bluetooth MIMO + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	, and the second
22	5G NR FR1 + 5G NR FR2	Yes	Yes	N/A	Yes	
23	5G NR FR1 + 2.4 GHz WLAN Ant 1 + 5G NR FR2	Yes	Yes	Yes	Yes	
24	5G NR FR1 + 2.4 GHz WLAN Ant 2 + 5G NR FR2	Yes	Yes	Yes	Yes	
25	5G NR FR1 + 2.4 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
26	5G NR FR1 + 2.4 GHz Bluetooth Ant 1 + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
27	5G NR FR1 + 2.4 GHz Bluetooth Ant 2 + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
28	5G NR FR1 + 2.4 GHz Bluetooth MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	_
29	5G NR FR1 + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
30	5G NR FR1 + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
31	5G NR FR1 + 2.4 GHz WLAN Ant 1 + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
32	5G NR FR1 + 2.4 GHz WLAN Ant 2 + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
33	5G NR FR1 + 2.4 GHz WLAN MIMO + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
34	5G NR FR1 + 2.4 GHz Bluetooth Ant 1 + 5 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
35	5G NR FR1 + 2.4 GHz Bluetooth Ant 2 + 5 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	Yes^	Yes	^Bluetooth Tethering is considered
36	5G NR FR1 + 2.4 GHz Bluetooth MIMO + 5 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	Yes	Yes	
37	5G NR FR1 + 2.4 GHz WLAN Ant 1 + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
38	5G NR FR1 + 2.4 GHz WLAN Ant 2 + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
39	5G NR FR1 + 2.4 GHz WLAN MIMO + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	
40	5G NR FR1 + 2.4 GHz Bluetooth Ant 1 + 6 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	N/A	Yes	^Bluetooth Tethering is considered
41	5G NR FR1 + 2.4 GHz Bluetooth Ant 2 + 6 GHz WLAN MIMO + 5G NR FR2	Yes^	Yes	N/A	Yes	^Bluetooth Tethering is considered
42	5G NR FR1 + 2.4 GHz Bluetooth MIMO + 6 GHz WLAN MIMO + 5G NR FR2	Yes	Yes	N/A	Yes	

NOTE:

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- 1. 5G NR mmW Operations are limited to Non-Standalone (EN-DC) operations only.
- 2. NR antenna arrays cannot transmit simultaneously.
- 3. LTE + 5G NR FR2 and 5G NR FR1 + 5G NR FR2 Scenarios are limited to EN-DC combinations with anchor bands as shown in the NR FR2 checklists.
- 4. 2.4 GHz WLAN, and 2.4 GHz Bluetooth share the same antenna path and cannot transmit simultaneously.
- 5. This device supports time averaging smart transmit algorithm in WWAN. Smart transmit adds directly the time-averaged RF exposure from 4G/5G NR FR1 and time-averaged RF exposure from 5G mmW NR FR2 to ensure that the normalized RF exposure from both 4G/5G NR FR1 and 5G mmW NR FR2 does not exceed FCC limit.

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1.7 Guidance Applied

- November 2017, October 2018, April 2019, November 2019 TCBC Workshop Notes
- SPEAG DASY6 System Handbook
- IEC TR 63170:2018
- FCC KDB 865664 D02 v01r04
- FCC KDB 447498 D01 v02r01

1.8 Bibliography

Table 1-9 Bibliography

Report Type	Report Serial Number
FCC SAR Evaluation Report (Part 1)	1M2109090103-01.A3L
Power Density Part 0 Test Report	
RF Exposure Part 2 Test Report	1M2109090103-25.A3L
RF Exposure Compliance Summary Report	1M2109090103-26.A3L
Power Density Simulation Report	
WIFI 6 GHz RF Exposure Report	1M2109090103-28.A3L

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2 MEASUREMENT SYSTEM

2.1 Measurement Setup

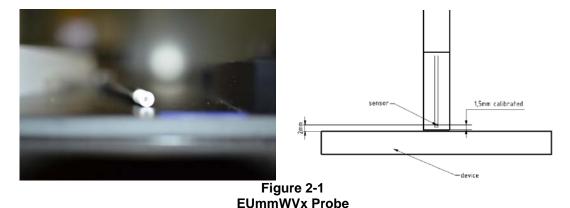
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Peak spatially averaged power density (psPD) measurements for mmWave frequencies were performed using the DASY6 with cDASY6 5G module. The DASY6 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of a high precision robotics system (Staubli), robot controller, desktop computer, nearfield probe, probe alignment sensor, and the 5G phantom. The robot is a six-axis industrial robot, performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).

2.2 SPEAG EUmmWVx Probe / E-Field 5G Probe

The EUmmWVx probe consists of two dipoles optimally arranged to obtain pseudo-vector information.

Frequency Range	750 MHz – 110 GHz
Dynamic Range	< 20 V/m - 10,000 V/m with PRE-10 (min < 50 V/m - 3,000 V/m)
Position Precision	< 0.2 mm (cDASY6)
Dimensions	Probe Overall Length: 320 mm Probe Body Diameter: 8 mm Probe Tip Length: 23 mm Probe Tip Diameter: Encapsulation 8 mm Distance from Probe Tip to Sensor X Calibration Point: 1.5 mm Distance from Probe Tip to Sensor Y Calibration Point: 1.5 mm
Applications	E-field measurements of 5G devices and other mm-wave transmitters operating above 10 GHz in < 2 mm distance from device (free-space) Power density, H-field and far-field analysis using total field reconstruction
Compatibility	cDASY6 + 5G-Module SW



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2.3 Peak Spatially Averaged Power Density Assessment Based on E-field Measurements

Within a short distance from the transmitting source, power density was determined based on both electric and magnetic fields. Generally, the magnitude and phase of two components of either the E-field or H-field were needed on a sufficiently large surface to fully characterize the total E-field and H-field distributions. Nevertheless, solutions based on direct measurement of E-field and H-field can be used to compute power density. The general measurement approach used for this device was:

- a) The local E field on the measurement surface was measured at a reference location where the field is well above the noise level. This reference level was used at the end of this procedure to assess output power drift of the DUT during the measurement.
- b) The electric field on the measurement surface was scanned. Measurements are conducted according to the instructions provided by the measurement system manufacturer. Measurement spatial resolution can depend on the measured field characteristic and measurement methodology used by the system. The planar scan step size was configured at $\lambda/4$.
- c) For cDASY6, H-field was calculated from the measured E-field using a reconstruction algorithm. As the power density calculation requires knowledge of both amplitude and phase, reconstruction algorithms can also be used to obtain field information from the measured E-field data (e.g. the phase from the amplitude if only the amplitude is measured). H-field and phase data was reconstructed from repeated measurements (three per measurement point) on two measurement planes separated by λ/4.
- d) The total Peak spatially averaged power density (psPD) distribution on the evaluation surface is determined per the below equation. The spatial averaging area, *A*, is specified by the applicable exposure limits or regulatory requirements. A circular shape was used.

$$psPD = \frac{1}{2A_{av}} \qquad \iint_{A_{av}} || Re\{E \times H^*\} || dA$$

- e) The maximum spatial-average on the evaluation surface is the final quantity to determine compliance against applicable limits.
- f) The local E field reference value, at the same location as step 2, was re-measured after the scan was complete to calculate the power drift. If the drift deviated by more than 5%, the power density test and drift measurements were repeated.

2.4 Reconstruction Algorithm

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Computation of the power density in general requires measurement information from the both E-field and H-field amplitudes and phases in the plane of incidence. Reconstruction of these quantities from pseudo-vector E-field measurements is feasible according to the manufacturer, as they are determined via Maxwell's equations. As such, the SPEAG reconstruction approach was based on the Gerchberg-Saxton algorithm, which benefits from the availability of the E-field polarization ellipse information obtained with the EUmmWVx probe.

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3 RF EXPOSURE LIMITS FOR POWER DENSITY

Uncontrolled Environment 3.1

UNCONTROLLED ENVIRONMENTS are defined as locations where there is the exposure of individuals who have no knowledge or control of their exposure. The general population/uncontrolled exposure limits are applicable to situations in which the general public may be exposed or in which persons who are exposed as a consequence of their employment may not be made fully aware of the potential for exposure or cannot exercise control over their exposure. Members of the general public would come under this category when exposure is not employment-related; for example, in the case of a wireless transmitter that exposes persons in its vicinity.

3.2 Controlled Environment

CONTROLLED ENVIRONMENTS are defined as locations where there is exposure that may be incurred by persons who are aware of the potential for exposure, (i.e. as a result of employment or occupation). In general, occupational/controlled exposure limits are applicable to situations in which persons are exposed as a consequence of their employment, who have been made fully aware of the potential for exposure and can exercise control over their exposure. This exposure category is also applicable when the exposure is of a transient nature due to incidental passage through a location where the exposure levels may be higher than the general population/uncontrolled limits, but the exposed person is fully aware of the potential for exposure and can exercise control over his or her exposure by leaving the area or by some other appropriate means.

3.3 RF Exposure Limits for Frequencies Above 6 GHz

Per §1.1310 (d)(3), the MPE limits are applied for frequencies above 6 GHz. Power Density is expressed in units of W/m² or mW/cm².

Peak Spatially Averaged Power Density was evaluated over a circular area of 4 cm² per interim FCC Guidance for near-field power density evaluations per October 2018 TCB Workshop notes.

> Table 3-1 Human Exposure Limits Specified in FCC 47 CFR §1.1310

Human Exposure to Radiofrequency (RF) Radiation Limits									
Frequency Range [MHz]	Power Density [mW/cm ²]	Average Time [Minutes]							
(A) Limits	For Occupational / Controlled	Environments							
1,500 – 100,000	5.0	6							
(B) Limits For	(B) Limits For General Population / Uncontrolled Environments								
1,500 – 100,000	1.0	30							

Note: 1.0 mW/cm² is 10 W/m²

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4 SYSTEM VERIFICATION

4.1 Test System Verification

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The system was verified to be within ±0.66 dB of the power density targets on the calibration certificate according to the test system specification in the user's manual and calibration facility recommendation. The 0.66 dB deviation threshold represents the expanded uncertainty for system performance checks using SPEAG's mmWave verification sources. The same spatial resolution and measurement region used in the source calibration was applied during the system check.

The measured power density distribution of verification source was also confirmed through visual inspection to have no noticeable differences, both spatially (shape) and numerically (level) from the distribution provided by the manufacturer, per November 2017 TCBC Workshop Notes.

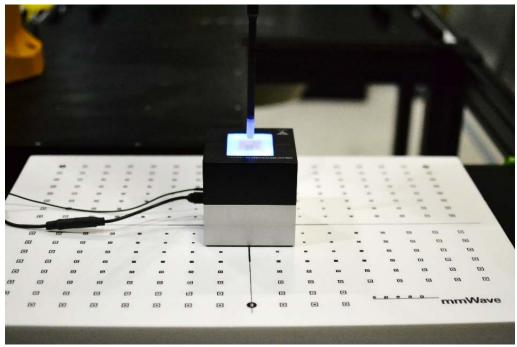


Figure 4-1
System Verification Setup Photo

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Table 4-1 30 GHz Verifications

	30 OHZ Vermications										
System Verification											
System	Frequency	Date Source Probe Normal psPD (W/m² over 4 cm²) Deviation (dB)	/m² over 4 cm²) Deviation (dB)		Total psPD (W/r	m² over 4 cm²)	Deviation (dB)	Plot#			
			S/N	S/N	Measured	Target	` '	Measured	Target		
Q	30	10/07/2021	1035	9389	31.40	31.00	0.06	31.70	31.00	0.10	
Q	30	10/19/2021	1035	9389	31.50	31.00	0.07	31.90	31.00	0.12	
Q	30	10/21/2021	1035	9389	31.70	31.00	0.10	32.10	31.00	0.15	
Q	30	10/25/2021	1035	9389	32.10	31.00	0.15	32.50	31.00	0.21	B1
Q	30	10/26/2021	1035	9389	31.40	31.00	0.06	31.80	31.00	0.11	
R	30	10/28/2021	1045	9523	31.80	32.70	-0.12	32.30	33.20	-0.12	B2
R	30	11/10/2021	1045	9523	31.40	32.70	-0.18	31.80	33.20	-0.19	В3
R	30	11/15/2021	1045	9523	31.60	32.70	-0.15	32.00	33.20	-0.16	

Note: A **10 mm distance spacing** was used from the reference horn antenna aperture to the probe element. This includes 4.45 mm from the reference antenna horn aperture to the surface of the verification source plus 5.55 mm from the surface to the probe. The SPEAG software requires a setting of "5.55 mm" for the correct set up.

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5 **POWER DENSITY DATA @ INPUT.POWER.LIMIT**

Power Density Results 5.1

Power density measurements were performed with DUT transmitting at input.power.limit for one single beam for each polarization (H & V) and one beam-pair, for each antenna on each worst-surface.

Table 5-1 5G mmWave NR Band n258

	MEASUREMENT RESU														
Band	Module	Antenna Type	Frequency	Channel	Beam ID 1	Beam ID 2	input.power.limit	Signal Type	DUT S/N	Power Drift	Distance	DUT Surface	Normal psPD	Total psPD	Plot #
		31.	MHz		V	Н	dBm	,,,,		dB	mm		mW/cm²	mW/cm²	
n258	М	Patch	25200.00	High	34	-	2.1	CW	UI20043M	-0.18	2	Back	0.264	0.329	
n258	М	Patch	25200.00	High	-	156	1.0	CW	UI20043M	0.13	2	Back	0.286	0.412	A1
n258	М	Patch	25200.00	High	28	156	-1.9	CW	UI20043M	-0.01	2	Back	0.158	0.247	
n258	М	Patch	24800.04	Mid	27	-	2.9	CW	UJ40648M	-0.10	10	Back	0.194	0.216	
n258	N	Patch	24350.04	Low	41	-	3.6	CW	UJ40648M	-0.05	2	Back	0.107	0.155	
n258	N	Patch	25200.00	High	-	159	2.5	CW	UI20043M	-0.04	2	Back	0.090	0.094	
n258	N	Patch	24350.04	Low	33	161	-0.2	CW	UI20043M	0.00	2	Back	0.097	0.115	
n258	N	Patch	24350.04	Low	29	157	-0.3	CW	UJ40648M	-0.05	10	Back	0.013	0.016	
n258	N	Patch	24350.04	Low	32	-	3.0	CW	UI20043M	-0.15	2	Right	0.209	0.257	
n258	N	Patch	25200.00	High	-	159	2.5	cw	UI20043M	0.17	2	Right	0.230	0.253	
n258	N	Patch	24350.04	Low	30	158	-0.8	CW	UI20043M	-0.01	2	Right	0.209	0.271	A2
	47 CFR §1.1310 - SAFETY LIMIT Spatial Average Uncontrolled Exposure / General Population							ē	Power Der 1 mW/cr averaged ove	m²					

Table 5-2 5G mmWave NR Band n261

	3G IIIIIWave NK Ba									IU IIZ	01				
							МЕ	EASUREN	IENT RESULT	rs					
Band	nd Module I	Antenna Type	Frequency	Channel	Beam ID	Beam ID 2	input.power.limit	Signal Type	DUT S/N	Power Distance	Distance	DUT Surface	Normal psPD	Total psPD	Plot #
		71	MHz		٧	Н	dBm	,,,		dB	mm		mW/cm²	mW/cm²	
n261	М	Patch	28299.96	High	27	-	2.4	CW	UI20043M	-0.06	2	Back	0.310	0.371	
n261	М	Patch	27924.96	Mid	-	156	1.0	CW	UI20043M	-0.20	2	Back	0.248	0.391	A3
n261	М	Patch	27924.96	Mid	28	156	-1.4	CW	UI20043M	-0.15	2	Back	0.252	0.359	
n261	М	Patch	27550.08	Low	-	164	1.9	CW	UJ40648M	-0.09	10	Back	0.284	0.301	
n261	N	Patch	28299.96	High	31	-	1.4	CW	UI20043M	0.06	2	Right	0.199	0.223	
n261	N	Patch	28299.96	High	-	167	2.0	CW	UI20043M	0.04	2	Right	0.312	0.349	A4
n261	N	Patch	28299.96	High	39	167	-1.8	CW	UI20043M	0.13	2	Right	0.205	0.233	
n261	N	Patch	27924.96	Mid	31	-	1.4	CW	UJ40648M	-0.06	10	Back	0.036	0.052	
	47 CFR §1.1310 - SAFETY LIMIT Spatial Average Uncontrolled Exposure / General Population								a	Power Dei 1 mW/ci veraged ove	m²				

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Table 5-3 5G mmWave NR Band n260

							og min	vavc	IN Dai	IU IIZ	00				
							ME	ASUREN	IENT RESULT	rs					
Band		Antenna Freq	Frequency	Channel	Beam ID	Beam ID 2	input.power.limit	Signal Type	DUT S/N	Power Drift	Distance	DUT Surface	Normal psPD	Total psPD	Plot #
		.,,,,,	MHz		V	Н	dBm	.,,,,		dB	mm		mW/cm²	mW/cm²	
n260	М	Patch	39949.92	High	25	-	4.8	CW	UI20043M	0.17	2	Back	0.403	0.458	A5
n260	М	Patch	38499.96	Mid	-	154	3.8	CW	UI20043M	-0.07	2	Back	0.302	0.364	
n260	М	Patch	38499.96	Mid	26	154	0.1	CW	UI20043M	0.02	2	Back	0.196	0.227	
n260	М	Patch	39949.92	High	35	163	0.9	CW	UJ40648M	-0.01	10	Back	0.189	0.206	
n260	М	Patch	39949.92	High	25	-	4.8	CW	UI20043M	-0.04	2	Left	0.203	0.241	
n260	М	Patch	39949.92	High	-	156	4.0	CW	UI20043M	0.18	2	Left	0.132	0.192	
n260	М	Patch	39949.92	High	28	156	0.4	CW	UI20043M	0.05	2	Left	0.134	0.152	
n260	N	Patch	37050.00	Low	32	-	1.0	CW	UI20043M	0.08	2	Right	0.075	0.155	
n260	N	Patch	38499.96	Mid	-	167	1.0	CW	UI20043M	-0.01	2	Right	0.184	0.214	A6
n260	N	Patch	37050.00	Low	29	157	-2.8	CW	UI20043M	0.04	2	Right	0.091	0.162	
n260	N	Patch	39949.92	High	39	167	-2.1	CW	UJ40648M	0.09	10	Back	0.033	0.036	
	47 CFR §1.1310 - SAFETY LIMIT Spatial Average Uncontrolled Exposure / General Population									Power Dei 1 mW/ci averaged over	m²				

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5.2 Power Density Test Notes

General Notes:

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- 1. The manufacturer has confirmed that the devices tested have the same physical, mechanical and thermal characteristics and are within operational tolerances expected for production units.
- 2. Batteries are fully charged at the beginning of the measurements. The DUT was connected to a wall charger for some measurements due to the test duration. It was confirmed that the charger plugged into this DUT did not impact the near-field PD test results.
- 3. Power density was calculated by repeated E-field measurements on two measurement planes separated by $\lambda/4$.
- 4. DUT was configured to transmit with a manufacturer provided test software to control specific antenna(s), Beam ID(s), and signal type to ensure the test configurations constant for the entire evaluation.
- 5. This device utilizes power reduction for some WLAN wireless modes and technologies for simultaneous transmission compliance. These mechanisms are assessed in the SAR Test Report.
- 6. Input.power.limit parameter for 5G mmW NR radio was calculated in RF Exposure Part 0 test report.
- 7. This device is enabled with Qualcomm® Smart Transmit feature to control and manage transmitting power in real time and to ensure that the time-averaged RF exposure from WWAN is in compliance with FCC requirements. Per FCC guidance for devices enabled with Qualcomm® Smart Transmit feature, 4G LTE/5G NR FR1 and 5G mmW NR FR2 simultaneous transmission scenario does not need to be evaluated under Total Exposure Ratio (TER). The validation of the time-averaging algorithm and compliance under the Tx varying transmission scenario for WWAN technologies are reported in Part 2 report.
- 8. Per FCC guidance for devices enabled with Qualcomm® Smart Transmit feature, simultaneous transmission analysis is evaluated by combining the exposure from each WWAN and WLAN antenna. 5G mmW NR and WLAN simultaneous transmission scenario is evaluated under the Total Exposure Ratio (TER) Appendix.
- 9. The Beam IDs with one of the highest initial simulated power density for that surface and distance was selected for Part 1 Power Density measurements.
- 10. The device was configured to transmit CW wave signal for testing. Per FCC guidance for devices enabled with Qualcomm® Smart Transmit feature, additional testing was not required for different modulations (CP-OFDM: QPSK, 16QAM, 64QAM, 256QAM, DFT-s-OFDM: PI/2 BPSK, QPSK, 16QAM, 64QAM, 256QAM), RB configurations, component carriers, channel configurations (low channel, mid channel, high channel) since the smart transmit algorithm monitors powers on a per symbol basis, which is independent of these signal characteristics.
- 11. The device was configured to MIMO configuration with H and V polarization beams transmitting together.
- 12. When additional sides are tested at a distance further than 2mm, the beam ID with the highest ratio of simulated power density of the tested distance to worst case 2mm was selected for power density measurements for that specific side and distance.

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COMBINED PD VERIFICATIONS

This device supports GEN2 Smart Transmit. The following verifications were performed per 80-w2112-4.

Measured psPD results in the below verifications were measured at a reduced power level as per the manufacturer. All psPD values were scaled to reflect the original input.power.limit (before permanent back-off applied) corresponding to the PD_design_target. The permanent back-off values are included in the Part 0 test report.

6.1 **Verification Criteria 1 (Power Density per beam):**

The measured psPD results from the previous section are confirmed to meet:

Measured psPD $\leq (b_i * PD_design_target + total uncertainty) < FCC psPD limit$

Table 6-1 5G mmWave NR mmWave Power Density Per Beam

	PD design	target (mW		Vave IVIX	0.631					
		certainty (· ·	2.0						
Band	Antenna	Antenna Type	Printed backoff value bj	Beam ID 1	Beam ID 2	Measured psPD	psPD scaled to input.power.limit without permanent backoff	bj * PD_design_target + total uncertainty	FCC psPD Limit	
						mW/cm²	mW/cm²	mW/cm ²	mW/cm²	
n258	М	Patch	0.9772	-	156	4.120	4.953	0.977	1	
n258	N	Patch	0.912	30	158	2.710	3.041	0.912	1	
n261	М	Patch	0.9772	-	156	3.910	4.701	0.977	1	
n261	N	Patch	0.912	-	167	3.490	3.916	0.912	1	
n260	М	Patch	0.9772	25	-	4.580	5.506	0.977	1	
n260	N	Patch	0.912	-	167	2.140	2.401	0.912	1	

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6.2 Verification Criteria 2 (combined Power Density):

Combined Power Density results in the below tables are confirmed to meet:

```
combined psPD = (c(p, j) * measured.psPD.beam_p + c(q, j) * measured.psPD.beam_q)

\leq PD\_design\_target + total uncertainty
```

where,

thereof, please contact INFO@PCTEST.COM.

```
meas. psPD. beam_i = measured \ 4cm^2 \ PD \ for \ beam \ i, i = p, q
c(i,j) = \text{contribution factor from beam}_i \ \text{to antenna}_i, i = p, q \ \text{and } j = 0,1
```

Beam_p = beam having the highest measured psPD among all beams tested for first antenna Beam_q = beam having the highest measured psPD among all beams tested for second antenna

Table 6-2
5G mmWave NR mmWave Highest Measured psPD

Band	Antenna	Antenna Type	Beam ID 1	Beam ID 2	Surface	Measured psPD	psPD scaled to input.power.limit without permanent backoff
						mW/cm²	mW/cm²
n258	М	Patch	-	156	Back	4.120	4.953
n258	N	Patch	41	-	Back	1.550	1.739
n258	N	Patch	30	158	Right	2.710	3.041
n261	М	Patch	-	156	Back	3.910	4.701
n261	N	Patch	-	167	Right	3.490	3.916
n260	М	Patch	25	-	Back	4.580	5.506
n260	М	Patch	25	-	Left	2.410	2.897
n260	N	Patch	-	167	Right	2.140	2.401

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Table 6-3
Combined Power Density Band n258

	Combined Power Density Band 11236							
		Contribution Factors	per module location					
Band	Beam ID	M	N					
		Back	Back					
JE0	156	1	0.0616					
n258	41	0.0046	0.5966					
	ned psPD //cm²)	4.961	1.343					
total un	gn_target + certainty] /cm²)	1	1					

		Contribution Factors per module location				
Band	Beam ID	М	N			
		Back	Right			
n258	156	1	0.0311			
11236	30/158	0.0024	1			
	ned psPD //cm²)	4.961	3.195			
total un	gn_target + certainty] //cm²)	1	1			

Table 6-4
Combined Power Density Band n261

	Combined i Ower Bensity Band 11201							
		Contribution Factors	per module location					
Band	Beam ID	M	N					
		Back	Right					
n261	156	1	0.0096					
11201	167	0.0049	1					
	ned psPD //cm²)	4.720	3.961					
total un	gn_target + certainty]	1	1					
(mW	/cm²)							

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Table 6-5
Combined Power Density Band n260

Combined Fower Density Band 11200					
		Contribution Factors per module location			
Band	Beam ID	M	N		
		Back	Right		
n260	25	1	0.0052		
n260	167	0.0003	1		
	ned psPD //cm²)	5.507	2.430		
[PD_design_target +		1	1		
total uncertainty] (mW/cm²)		1	1		

		Contribution Factors per module location		
Band	Beam ID	M	N	
		Left	Right	
n260	25	0.1722	0.0052	
11200	167	0.0003	1	
	ned psPD //cm²)	0.500	2.416	
total un	gn_target + certainty] /cm²)	1	1	

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EQUIPMENT LIST

Table 7-1 **5G mmWave NR Equipment List**

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
-	WL25-1	Conducted Cable Set (25GHz)	N/A	N/A	N/A	WL25-1
-	WL40-1	Conducted Cable Set (40GHz)	N/A	N/A	N/A	WL40-1
Agilent	N9038A	MXE EMI Receiver	N/A	N/A	N/A	MY51210133
Agilent	N9030A	PXA Signal Analyzer (44GHz)	N/A	N/A	N/A	MY52350166
EMCO	3160-09	Small Horn (18 - 26.5GHz)	N/A	N/A	N/A	00135427
Emco	3116	Horn Antenna (18 - 40GHz)	N/A	N/A	N/A	9203-2178
Rohde & Schwarz	SFUNIT-Rx	Shielded Filter Unit	N/A	N/A	N/A	102133
Rohde & Schwarz	FSW67	Signal / Spectrum Analyzer	N/A	N/A	N/A	103200
SPEAG	EUmmWV3	EUmmWV3 Probe	11/16/2020	Annual	11/16/2021	9389
SPEAG	SM 003 100 AA	30 GHz System Verification Ka- Band Source Antenna	02/10/2021	Annual	02/10/2022	1035
SPEAG	DAE4ip	Dasy Data Acquisition Electronics	11/17/2020	Annual	11/17/2021	1638
SPEAG	EUmmWV4	EUmmWV4 Probe	01/11/2021	Annual	01/11/2022	9523
SPEAG	SM 003 100 AA	30 GHz System Verification Ka- Band Source Antenna	12/10/2020	Annual	12/10/2021	1045
SPEAG	DAE4ip	Dasy Data Acquisition Electronics	11/17/2020	Annual	11/17/2021	1639
SPEAG	DAE4	Dasy Data Acquisition Electronics	09/15/2021	Annual	09/15/2022	1449
Emco	3115	Horn Antenna (1-18GHz)	N/A	N/A	N/A	9704-5182
Keysight Technologies	N9030A	3Hz-44GHz PXA Signal Analyzer	N/A	N/A	N/A	MY49430494
Keysight Technologies	N9030A	3Hz-44GHz PXA Signal Analyzer	N/A	N/A	N/A	MY49430244
Rohde & Schwarz	180-442-KF	Horn (Small)	N/A	N/A	N/A	U157403-01
Rohde & Schwarz	ESU26	EMI Test Receiver (26.5GHz)	N/A	N/A	N/A	100342
Rohde & Schwarz	SFUNIT-Rx	Shielded Filter Unit	N/A	N/A	N/A	102134
Sunol	JB5	Bi-Log Antenna (30M - 5GHz)	N/A	N/A	N/A	A051107
Virginia Diodes Inc	SAX252	Spectrum Analyzer Extension Module	N/A	N/A	N/A	SAX252
Virginia Diodes Inc	SAX253	Spectrum Analyzer Extension Module	N/A	N/A	N/A	SAX253
Virginia Diodes Inc	SAX254	Spectrum Analyzer Extension Module	N/A	N/A	N/A	SAX254

Note:

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^{1.} Each equipment item was used solely within its respective calibration period.

MEASUREMENT UNCERTAINTIES

a	b	С	d	e	f =	g
					c x f/e	
	Unc.	Prob.			u _i	
Uncertainty Component	(± dB)	Dist.	Div.	Ci	(± dB)	Vi
Measurement System	I					
Calibration	0.49	N	1	1	0.49	∞
Probe Correction	0.00	R	1.73	1	0.00	∞
Frequency Response	0.20	R	1.73	1	0.12	∞
Sensor Cross Coupling	0.00	R	1.73	1	0.00	∞
Isotropy	0.50	R	1.73	1	0.29	∞
Linearity	0.20	R	1.73	1	0.12	∞
Probe Scattering	0.00	R	1.73	1	0.00	∞
Probe Positioning offset	0.30	R	1.73	1	0.17	∞
Probe Positioning Repeatability	0.04	R	1.73	1	0.02	∞
Sensor MechanicalOffset	0.00	R	1.73	1	0.00	∞
Probe Spatial Resolution	0.00	R	1.73	1	0.00	∞
Field Impedence Dependance	0.00	R	1.73	1	0.00	∞
Amplitude and Phase Drift	0.00	R	1.73	1	0.00	∞
Amplitude and Phase Noise	0.04	R	1.73	1	0.02	∞
Measurement Area Truncation	0.00	R	1.73	1	0.00	∞
Data Acquisition	0.03	N	1	1	0.03	∞
Sampling	0.00	R	1.73	1	0.00	∞
Field Reconstruction	0.60	R	1.73	1	0.35	∞
Forward Transformation	0.00	R	1.73	1	0.00	∞
Power Density Scaling	0.00	R	1.73	1	0.00	∞
Spatial Averaging	0.10	R	1.73	1	0.06	∞
System Detection Limit	0.04	R	1.73	1	0.02	∞
Test Sample Related						
Probe Coupling with DUT	0.00	R	1.73	1	0.00	∞
Modulation Response	0.40	R	1.73	1	0.23	∞
Integration Time	0.00	R	1.73	1	0.00	∞
Response Time	0.00	R	1.73	1	0.00	∞
Device Holder Influence	0.10	R	1.73	1	0.06	∞
DUT alignment	0.00	R	1.73	1	0.00	∞
RF Ambient Conditions	0.04	R	1.73	1	0.02	∞
Ambient Reflections	0.04	R	1.73	1	0.02	∞
Immunity/Secondary Reception	0.00	R	1.73	1	0.00	∞
Drift of DUT	0.21	R	1.73	1	0.12	∞
Combined Standard Uncertainty (k=1)	<u> </u>	RSS			0.76	∞
Expanded Uncertainty		k=2			1.52	
(95% CONFIDENCE LEVEL)						

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9 CONCLUSION

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9.1 Measurement Conclusion

The power density measurements and total exposure ratio analysis indicate that the DUT complies with the RF radiation exposure limits of the FCC, with respect to all parameters subject to this test. These measurements were taken to simulate the RF effects of RF exposure under worst-case conditions. Precise laboratory measures were taken to assure repeatability of the tests. The results and statements relate only to the item(s) tested.

Please note that the RF Exposure and distribution of electromagnetic energy in the body are very complex phenomena that depend on the mass, shape, and size of the body, the orientation of the body with respect to the field vectors, and the electrical properties of both the body and the environment. Other variables that may play a substantial role in possible biological effects are those that characterize the environment (e.g. ambient temperature, air velocity, relative humidity, and body insulation) and those that characterize the individual (e.g. age, gender, activity level, debilitation, or disease). Because various factors may interact with one another to vary the specific biological outcome of an exposure to electromagnetic fields, any protection guide should consider maximal amplification of biological effects as a result of field-body interactions, environmental conditions, and physiological variables.

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